

June 2007

### BSP51

# **NPN Darlington Transistor**

This device is designed for applications requiring extremly high current gain at collector currents to 500mA. Sourced from process 03.



1. Base 2. Collector 3. Emitter

### Absolute Maximum Ratings ${}^{\star}T_a = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CES</sub>	Collector-Emitter Voltage	80	V
$V_{CBO}$	Collector-Base Voltage	90	V
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V
I <sub>C</sub>	Collector Current (Continuous)	500	mA
T <sub>J,</sub> T <sub>STG</sub>	Junction Temperature, Storage Temperature	-55 ~ <b>+</b> 150	°C

<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Symbol

## Electrical Characteristics \* Ta = 25°C unless otherwise noted **Parameter**

Off Characteristics					
V <sub>(BR)</sub> CBO	Collector-Base Breakdown Voltage	Ic = 100 μA, Iε = 0	90		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	5.0		V
Ices	Collector Cutoff Current	Vce = 80 V, IBE = 0		10	μА
<b>І</b> ЕВО	Emitter Cutoff Current	VEB = 4.0 V, Ic = 0		10	μΑ

**Test Condition** 

MIN

MAX

**Units** 

### On Characteristics

hfE	DC Current Gain	Ic = 150 mA, VcE = 10 V Ic = 500 mA, VcE = 10 V	1000 2000		
VcE(sat)	Collector-Emitter Saturation Voltage *	Ic = 500 mA, I <sub>B</sub> = 0.5 mA		1.3	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage *	Ic = 500 mA, I <sub>B</sub> = 0.5 mA		1.9	V

<sup>\*</sup> Pulse Test: Pulse Width≤300μs, Duty Cycle≤2%

<sup>1)</sup> These ratings are based on a maximum junction temperature of 150 degrees C.

<sup>2)</sup> These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

# Thermal Characteristics ${}^{\star}T_a = 25^{\circ}C$ unless otherwise noted

Symbol	Characteristic	Max	Units
Po	Total Device Dissipation	1000	mW
	Derate above 25°	8.0	mW/°C
R $\Theta$ JA	Thermal Resistance, Junction to Ambient	125	°C/W

<sup>\*</sup>Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06".





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